2 METER BAND SSB TRANSCEIVER

IC-202E



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TABLE OF CONTENTS

11.		1 2 3 4
VI.	DESCRIPTION OF CONTROLS AND CONNECTIONS	7
2008110		
X. XI.		22

SECTION I INTRODUCTION

Congratulations on the purchase of the IC-202E portable 2 meter SSB transceiver. The IC-202E was designed to be operable anywhere like most portables, but we also included features like a very effective noise blanker, RIT, S&RF meter, and a full 3 watts output. Two built-in crystals in the stable VXO allow operation between 144.00 and 144.40MHz. If you wish to expand the range of the IC-202E, we have also provided 2 spare crystal sockets for your convenience. With a slight retuning of the IC-202E, and installation of a special crystal, you may also work through OSCAR in USB.

The aluminum die cast frame provides a very strong yet light housing for the 2 circuit boards, and the aluminum sides snap off easily if service is ever necessary or to change batteries.

The IC-202E operates on 9 inexpensive C cell batteries, or an external 13.8V DC source. The IC-202E will also operate on nicad batteries, contained in the BC-20 nicad battery/charger kit. For AC operation, we recommend the IC-3PS which not only provides power for the IC-202E, but also doubles as a stand and holder for the IC-20L 10 watt linear amplifier.

You can use the built-in whip antenna for portable use, or a flexible antenna such as the IC-FA1. An external antenna connects to the antenna connector on the back of the IC-202E.

We are sure that you will have years of lasting enjoyment from your IC-202E, manufactured by the leader in communication equipment: Inoue Communication Equipment Corporation.



SECTION II SPECIFICATIONS

General:

Number of Semi-conductors

Frequency Coverage Frequency Stability Antenna Impedance Power Supply Requirements Current Drain

Dimensions Net Weight

Transmitter: Emission Mode

RF Power Output

Carrier Suppression Unwanted Sideband Suppression Spurious Radiation Microphone

Receiver: Receiving System Intermediate Frequency Receiving Mode Spurious Response Rejection Ratio Sensitivity Selectivity

Audio Output Audio Output Impedance Transistors 19 FET 7 7 IC 33 Diodes 144-146MHz Less than 200Hz per hour at +25°C 50 ohms unbalanced DC 13.8V±15% Negative Ground 800mA max Transmitting: A3J Approx. 540mA A1 Approx, 750mA Receiving: At max audio approx 250mA With no signal approx 90mA Dial Light: Approx 40mA 183mm(H) x 61mm(W) x 162mm(D) 2.0KGs including batteries.

A3J (USB) and A1 A3J 3W (PEP) A1 3W More than 40dB down More than 40dB down at 1000Hz AF input More than 60dB below peak power Impedance: 600 ohms Input level: 10mV typical Dynamic or optional Electret condenser microphone

Single Conversion Super Heterodyne 10.7MHz A3J (USB) and A1 More than 60dB Less than 0.5µV for 10dB S+N/N ±1.2KHz at -6dB ±2.4KHz at -60dB More than 1W 8 ohms

144.00–144.40MHz built-in (2 Crystals). Each crystal gives 200KHz continuous coverage. Two spare crystal sockets are provided for additional frequency ranges between 144.40–146.00MHz. An external VFO connection is also provided.

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1. Dynam

- 2. Microp
- 3. Should
- 4. Power

How to fit





SECTION III ACCESSORIES

Various accessories are packed with your transceiver. Be sure not to overlook anything. Also it's a good idea to keep packing cartons in case of moving or if return for service is necessary.



BATTERY INSTALLATION

Dry Battery:

Place the function switch in the OFF position. Remove the side that covers the battery case and speaker. Install the batteries into the battery tubes (three in each) taking care to observe the same direction (polarity).

Carefully install the battery tubes in the manner shown in photograph 1, placing the last three batteries in the inner column. Again take care to observe polarity, and place the battery tubes on top of the ribbon so when the batteries need to be removed, a simple pull on the ribbon will make removal easier. With the batteries properly in place, carefully replace the side cover.



Nickel-Cadmium Batteries and Charger Installation

Nickel-Cadmium Batteries and Charger:

First, install the charger in the battery case (the speaker side) of the transceiver housing as shown in photograph 2. The polarity of the switch end of the charger must be positive and on the case side, negative. Accordingly the negative polarity must be connected to the spring side of the battery case.

Next insta Make certa batteries in or from th the cover h

WHEN TO

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- * Be

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EXTERNA

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- 2. Correc reverse operat
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- 4. The o plug t body fuse ()

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Next, install five nickel-cadmium batteries in the battery tubes in the same direction. Make certain the (-) minus side is next to the spring. After installation of the charger and batteries in the case, connect the connector to the socket of the charger (i.e., the connector from the transceiver housing). Make sure the switch of the charger is on, then install the cover housing as before.

WHEN TO REPLACE BATTERIES

When the power pilot lamp does not light up with the power switch on, or when it lights up during reception and goes out during transmission, the batteries are exhausted. Use batteries of the same type, for mixed types might cause leakage. Replace worn batteries with a complete new set of nine. If used with old batteries, the life of new ones might be shortened. Battery life is shortened more by transmitting than by receiving, since several times more current is drawn in transmit. To prolong battery life, therefore, practice as follows:

- * Try to minimize the transmit period.
- * Keep the transmission output on LOW as much as possible.
- * Reduce volume during reception.
- * Be sure to cut off power source when set is not used.

More working hours are available if high-performance batteries such as Alkaline type are employed.

EXTERNAL POWER PLUG CONNECTION

External Power Source

For use at home or in the car, please use the external power source which assures you of stable communication without concern about battery consumption.

- Use either a regulated power supply or car battery of 13.8V DC and of over 1A current capability. (Though this transceiver may work at 11 to 15 VDC, use it preferably at the rated voltage.)
- Correctly connect the external supply plug, as shown in the figure. If polarity is reversed, source power is cut off by the protection circuit and the unit will not operate.
- 3. When the transceiver is kept out of use for a prolonged period, the unit is operated for extended periods by external power only, or when the batteries are exhausted etc., remove the batteries to protect the unit from possible damage by battery leakage.
- 4. The outside electrode of the power plug is + (Positive). Be careful not to short the plug to the chassis frame, etc. When used in the car, don't short the plug to the car body or to the transceiver body itself, but connect it to the car battery through its fuse (1A-2A).

External DC Plug Wiring Diagram



SECTI

FOR OUTDOOR USE

- 1. Insert the supplied batteries. (Refer to "How to insert batteries").
- Attach the supplied shoulder strap through the fixture of the body (as shown in the drawings on page 3).
- Fully extend the whip antenna for operation, or install the flexible antenna. Keep the collapsible antenna depressed when the set is not in use so that it will not be damaged.

FOR USE IN THE CAR

- 1. Don't place the unit near the outlet of heaters, air-conditioners, etc.
- 2. Install the unit in a convenient place to avoid disrupting safe driving.
- 3. For the best power source, connect to the car battery through the fuse (1A-2A).
- Firmly ground to the car body a mobile antenna (e.g. whip antenna) that requires grounding.



FOR FIXED USE

- Don't install the unit in places exposed to rain, water splash, direct sunshine, dust, vibration, or heat.
- Use a high performance external antenna as recommended. When doing this, be sure to depress the whip antenna into the body.
- 3. For fixed use, an external power supply is more economical than batteries.
- Use of the linear amplifier IC-20L and AC power supply IC-3PS give excellent performance for fixed use.

HOW TO USE EXTERNAL ANTENNA

1. Select a high performance antenna (a multi-element beam or gain antenna) and set it up in the highest possible position. Tightly connect the antenna so that performance will not be affected by weather or vibration. The matching impedance is designed to be 50Ω . 1. POW Show

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 S & I Indic trans

SECTION V DESCRIPTION OF CONTROLS AND CONNECTIONS



 POWER INDICATOR LED Shows when power is applied to the IC-202E.

2. S&RF METER

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Indicates the relative signal strength of incoming signals and output power of transmitted signals.

			11
-		14.	SNAP
3.	DIAL SCALE		Convei
	The dial is divided into 10KHz increments with a total coverage of 200KHz. The operating frequency is read by adding the frequency shown on the dial to that		To rer
	shown on the crystal switch, or in the case of the spare crystals, by adding the dial		the ba
	reading to the frequency of the crystal installed.		the sn
	reading to the frequency of the crystal instance.		moved
4.	TUNING KNOB		you h groove
	Selects the Frequency.		center
	Beleta tio rioquello,		Note:
5.	RIT		the sni
	Independently swings the receiver frequency ±3KHz so that signals that are slightly		the second
	off frequency may be tuned for clarity without affecting the transmitting frequen-	15.	SHOU
	cy.	Canal Sec.	Conne
			carryii
6.	MODE SWITCH		
	In the CW-T position the transmitter will transmit when the CW key makes contact.	16.	EXTE
	In the REC position both SSB and CW signals can be received. In the CW-T posi-		Accep
	tion, the microphone is disconnected from the circuit.		source
7.	NOISE BLANKER SWITCH	17.	WHIP
\$25.5	In the NB position, the noise blanker is put into the circuit and noise pulses will be	1200	When
	reduced.		collap
			Use ci
8.	VOLUME CONTROL		antenr
	Controls the audio output level.		
			FLEX
9.	CRYSTAL SWITCH		A flex.
	Selects the crystal to be used in the VXO.		used.
24			and sc
10.	FUNCTION SWITCH	10	
	Turns the power on and off and in the light position, turns on the meter light. In	18.	
	EXT VFO position, the frequency of the IC-202E can be controlled by an exter- nal VFO. (see page 10).		When
	hal VPO, (see page 10).	10	EXTE
Ц.	EXTERNAL SPEAKER JACK	15.	Any v
3.4.4	An external speaker can be connected here. The impedance of the speaker should		here,
	be 8 ohms. With the external speaker connected, the built-in speaker will be dis-		disable
	abled.		the ex
		- 225	CONSIGNATION OF THE
12.	KEY JACK	20.	2.5
	Accepts a CW key for CW operation.		An ex
13.	MICROPHONE CONNECTOR		anten
15.	A 600 ohm microphone is connected here.	21.	IDEN
	A 600 binn microphone is connected nere.	238-5	State

14. SNAP LOCKS

Convenient snap-locks hold the sides in place. To remove them for any service or to replace the batteries, simply pull out on the center of the snap-locks and the cover can easily be removed. When replacing the covers be sure that you have placed the covers properly in the grooves provided, then push down on the center of the snap-lock (see page 4).

Note: when the sides are placed in the grooves, the snap-lock center must be pulled out.

- SHOULDER STRAP BRACKET Connect the shoulder strap here for easy carrying (see page 3).
- EXTERNAL VFO SOCKET Accepts plug from an external frequency source.

17. WHIP ANTENNA

When not in use, the antenna should be fully collapsed. Extend completely for operation. Use care when expanding or compressing the antenna.

FLEXIBLE ANTENNA (see page 26).

A flexible antenna, such as the IC-FA1, can be used. Unscrew the whip antenna from the set and screw the flexible antenna in its place.

18. MICROPHONE HANGER

When not in use, the mike can be hung out of the way.

19. EXTERNAL POWER SUPPLY JACK

Any well regulated power supply with an output of 13.8 volts can be connected here, instead of using the batteries installed. Inserting the power plug into the jack disables the internal battery source. When the BC-20 nicad battery pack is used, the external power source will charge the batteries.

20. EXTERNAL ANTENNA RECEPTACLE

An external antenna of 50 ohms impedance can be connected here. If an external antenna is used, the built-in whip should be completely collapsed.

21. IDENTIFICATION PLATE

States model number and serial number.



SECTION VI OPERATION

- After the batteries have been installed, or the IC-202E is connected to an external power source, turn the function switch on. If the surrounding light is too dim to see the S & RF meter, turn the switch to the LIGHT position, and the meter will be illuminated.
- Extend the whip antenna its full length, or if you wish to use an external antenna, connect the cable to the EXT antenna connector on the back of the IC-202E.
- 3. Connect the microphone to the MIC jack on the front panel.
- If you wish to use the CW mode of transmission, connect a key to the KEY jack on the front panel. You do not have to disconnect the microphone for CW operation.

Key Wiring Diagram



- 5. Place the mode switch in the proper position for the portion of the 2 meter band you wish to operate in, whether it be CW or SSB. If you wish to operate outside of the 144.00 144.40MHz portion of the band, it will be necessary for you to install an additional crystal in one of the spare crystal sockets provided for this purpose. See page 11 for an explanation of how this is done. Crystals can be ordered from your authorized ICOM distributor or wholesaler.
- 6. Turn the tuning knob until you reach the desired frequency or a signal is heard. Adjust the volume control for a comfortable level of listening. If operating SSB, you may wish to place the Noise Blanking switch in the NB position. This activates the noise blanking circuit which will suppress noise pulses. After selecting the operating frequency, if the received signal seems to drift, adjust the RIT control until the signal is again clear.
- 7. For SSB operation, hold the microphone close to your mouth, push the PTT switch on the microphone, and speak in a clear, normal tone of voice. For CW operation, after connection of your KEY, place the CW-T switch in the CW-T position and the IC-202E will transmit when the KEY contacts are closed. To receive, place the switch back in the REC position.
- 8. For operation with an external VFO, remove the rubber plug in the side of the IC-202E, and place the function switch in the EXT VFO position. The input frequency should be -133.3MHz -135.3MHz, 50 Ω , 300MV for 144.00 -146.00 MHz.-,

A/B POSIT

The IC-202 144.40MH band, all th crystal soch work the 1

INSTRUCT

Crystals 36 144.20 (36 crystal soc operating 6 cent crysta

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For other will proba realignmen necessary. Xtal No.

36-1 36-2 36-3 36-4 36-5 36-6

> * Sup ** For

Note:a. b.

A/B POSITION SPARE CRYSTALS

The IC-202E comes with 2 crystals installed in the VXO for operation between 144.00–144.40MHz with each crystal covering 200KHz. If you wish to work another part of the band, all that is needed is to install the proper frequency crystal in either the A or B spare crystal socket, tweak it, and you are ready for operation. Also a crystal can be installed to work the 145.80–146.00MHz portion of the band if you want to use OSCAR.

INSTRUCTIONS FOR INSTALLATION

Crystals 36-1 and 36-2 are already installed in the crystal sockets. These are for 144.00–144.20 (36-1) and 144.20–144.40MHz (36-2). Installing additional crystals in the spare crystal sockets in some positions and / or combinations may cause the output level of the operating crystal to decrease. This is due to absorption of some of the energy by the adjacent crystal.

	SPARE S	OCKET
	А	В
COMBINATION OF	36-3	x
CRYSTALS	36-5	×
	36-6	х
	x	36-4
	x	36-5
	x	36-6
	36-3	36-4
	36-3	36-6
	36-5	36-4
1	36-6	36-4

BE SURE TO FOLLOW THE CHART EXACTLY AS TO POSITION AND COMBINA-TION OF THE SPARE CRYSTALS TO OBTAIN THE OPTIMUM PERFORMANCE.

For other combination of crystals than those listed, a slight modification or realignment will probably be required. For communication through OSCAR (145.80–146.00MHz) realignment of various parts besides the readjustment of the oscillator frequency will be necessary.

Xtal No.	Center Freq.	Range	Type	Basic Freq.
36-1	144.100MHz	144.000-144.200MHz	HC-18/U	14848.83KHz*
36-2	144.300	144.200-144.400	HC-18/U	14871.06 *
36-3	144.500	144,400-144,600	HC-25/U	14893.28
36-4	144.700	144.600-144.800	HC-25/U	14915.50
36-5	144.900	144.800-145.000	HC-25/U	14937.72
36-6	145.900MHz	145.800-146.000MHz	HC-25/U	15048.83KHz**

* Supplied in the transceiver

** For OSCAR use.

Note: a. CL is 20 PF, with regard to the crystal load capacitance.

b. The frequency of the crystal oscillator (basic frequency) does not correspond to the oscillation frequency in the circuit.

SECTION VII THEORY

CIRCUITS

Section IX shows a block diagram of the IC-202E.

The receiving section is a single conversion super heterodyne, employing a wide band variable crystal oscillator (VXO) as the local oscillator. The transmitting section is a single conversion system which employs a filter-type SSB generator using a 10.7MHz crystal filter and the same local oscillator as the receiving section. A double-balanced mixer is used for the transmitting mixer to minimize spurious radiation. Although a portable unit, the IC-202E also features built-in circuits such as RIT, AGC, ALC, and a noise blanker.

This transceiver can be used with ease outdoors, in the car, or as a fixed station since it may be powered either with its batteries or with 13.8V external power source.

RECEIVING CIRCUIT

The signal from the whip antenna or antenna terminal passes through the harmonic filter, through the T/R switching diode D25 (MI301) amplified by RF amplifier Q2 (3SK40) and is then fed to the gate of mixer Q3 (2SK49). The switching diode is turned on by T/R control Q1 (2SA750), and D25 is turned on with forward voltage bias thus directing the input signal to Q2.

During transmission, the Receiver section +9V goes to zero to turn off Q1, and forward voltage bias is not applied to D25. At the same time, the transmit output is switched around Q2 to the antenna system. D25 is turned off as reverse bias is generated when the transmit signal is present. The 133MHz local oscillator output from the VXO is injected to mixer Q3 source. The resultant conversion is an IF Frequency of 10.7MHz.

The IF signal passes through the diode switch D1 (1SS53), which serves as both transmitreceive switch and noise blanker gate, the IF selectivity is obtained by the 10.7MHz crystal filter, then passes the switching diode D3 (1SS53) and is amplified up to a suitable level by the IF amplifiers consisting of Q6 (MEM616), Q7 (MEM616) and IC1 (LA1221). The output of IC1 is applied to the demodulation and AGC circuits.

The demodulation circuit is a ring demodulator composed of D6 to D9 (1N60's) which uses the 10.6985MHz from the BFO to generate the resultant audio signal. Higher audio frequencies of the demodulated signal are cut off by a low-pass filter consisting of C39, L11 and C40. The volume control (R-1) adjusts this output level which is fed to AF amplifier IC2 (μ PC575C2) providing 1 watt of audio.

The network R32 and D29 (1S1555) provides positive bias to IC2 for muting audio during transmit and silent transmit-receive switching.

NOISE BLANKER

A part of the IF signal is picked up at the drain of mixer Q3, amplified by IC3 and IC4 (LA1221's), and detected by D11(1N60). This detected output is separated into signal audio components, and pulse components (noise). The signal component is amplified by Q5 (2SC945) and provides AGC control to IC3.

The noise pulse component turns on Q5 (2SC945), and as long as noise exists, turns off

D1 by grou transferred t

AGC CIRCU A part of th R39 to be c bias voltage D13, and th

In the prese because D1emitter is n each amplif of a dischar

When the s through R5 voltage chai fast attack a

TRANSMIT The small Higher or tenuated b amplifier IC

This AF siq (SN76514N amplifier Q crystal filte SSB (USB)

This 10.7M (SN76514N (USB) sign minimizes s

In addition a band-pass is linearly : Higher harr to C144. T by R90. It

ALC CIRCI The ALC (put, rectifi voltage to t D1 by grounding the anode of the noise blanker gate diode D1, thus the noise is not transferred to the crystal filter.

AGC CIRCUIT

A part of the IF signal is picked up from the IF amplifier IC1 and passes through C73 and R39 to be detected by D13 (1N60), D14 and D15 (1S2473's). When no signal is received, bias voltage is applied to the base of AGC control Q11 (2SC945) through R51, D14 and D13, and the potential at the emitter of Q11 goes to nearly zero.

In the presence of a signal, C69 which is connected to Q11 base is first negatively charged because D14 is turned on, and so Q11 is turned off. Also, C70 which is connected to Q11 emitter is negatively charged through D15 up to a voltage determined by the loop gain of each amplifier of RF and IF, and C70 is kept at the achieved voltage due to the absence of a discharge circuit.

When the signal diminishes, the negative voltage charged in C69 is gradually discharged through R51 and drops down to a voltage where Q11 is turned on. Then the negative voltage charged in C70 is rapidly discharged through Q11, thus the AGC time constant of fast attack and slow release is effected.

TRANSMITTING CIRCUIT

The small signal from the microphone is adjusted by the mike gain adjustment R61. Higher or lower frequencies outside desirable communication frequency range are attenuated by R65, C80 and C79, and the remaining frequencies are amplified by AF amplifier IC5 (μ PC566H).

This AF signal and BFO output (10.6985MHz) are fed to the balanced modulator IC6 (SN76514N). The resulting carrier suppressed double sideband signal is amplified by IF amplifier Q16 (2SK19). The unwanted side band is then removed by the 10.7MHz crystal filter where it passes through the diode switch D2 (1SS53) to become a 10.7MHz SSB (USB) signal.

This 10.7MHz signal passes the diode switch D4(ISS53) to the transmit mixer IC7 (SN76514N). The L.O. of 133MHz from VXO unit is then combined to become the SSB (USB) signal of 144MHz. The transmit mixer IC7 is a double-balanced mixer, which minimizes spurious radiation.

In addition, the output circuits of IC7 and the 144MHz amplifier Q17 (3SK37) provides a band-pass filtering which further minimizes spurious radiation. This 144MHz SSB signal is linearly amplified by Q18 (2SC383), Q19 (2SC998), and Q20 (2SC1947) respectively. Higher harmonics are suppressed by the low-pass filter composed of L27, L28 and C140 to C144. The resultant output power is 3 Watts PEP. PA Q20 idling current is adjusted by R90. It is preset at 30mA.

ALC CIRCUIT

The ALC (Automatic Level Control) circuit picks out a part of the drive stage Q19 output, rectifies it by D20 (1S2473) and D21 (1N60), and applies the obtained negative voltage to the transmit IF amplifier Q16 gate to control circuit gain.

CW TRANSMISSION

For CW transmission, the voltage exerted on AF amplifier IC5 is reduced. At the same time the voltage to BFO frequency shift switch Q8's (2SC945) base is also reduced to turn it off so that C62 is in series as a part of the BFO crystal oscillator to shift the frequency about 1 KHz upward, which is within the crystal filter passband. Also, at the same time, the 5th Pin of the balanced modulator, IC6, is supplied with a voltage, which makes the modulator unbalanced, so that the BFO frequency appears unsuppressed at the output. Consequently, these signals are amplified by the transmit IF amplifier Q16 and pass through the crystal filter, transmit mixer IC7 and forward as in the SSB mode. Keying is done by Q17 source and Q18 emitter.

COMMON CIRCUIT

BFO

The BFO is a non-adjustable oscillator Q9 (2SC945). The crystal unit X1 has a load capacity of 25pF and operate at 10.6985MHz in the SSB mode. The change in BFO Frequency is explained under "CW transmission". The BFO output buffer is Q10 (2SC945).

METER CIRCUIT

This circuit permits use of single meter as an S-meter during reception and as an output level meter during transmission.

A bridge circuit composed of R49 and R48 is connected to the power source, stabilized by Zener diode D28 (WZ056), and the IF amplifier Q7 source. AGC voltage is generated by input signals reducing Q7's source voltage, thus unbalancing the bridge causing an upscale meter reading.

The S-meter is adjusted for its zero point by R48, and for its full scale point by R50.

For the output level meter, the output detection diode D22 (1N60) is coupled with L26 to partly rectify the RF output, thus giving an upscale relative output indication.

The extent of the meter indication can be adjusted by changing the degree of coupling of D22 and L26.

POWER SOURCE AND TRANSMIT/RECEIVE CHANGE-OVER CIRCUIT

The power source voltage (13.8V) supplied from either built-in batteries or external power connected to J10.

This voltage is directly applied to the AF power amplifier IC2 in the receiver section as well as to the collector of Q18, Q19 and Q20 in the power amplifier section.

Other circuits are fed with voltage from the voltage regulator circuits. The voltage regulator circuit for the VFO unit BFO and AGC circuits is derived from 13.8V to the Zener diode D19 (XZ076) and power-source indicating lamp D-2 (light-emitting diode TLR-102), resulting in stabilized voltage of about 9.6V which becomes a reference level at D19's cathode. This voltage is applied to Q15's (2SC1209) base, and a regulated voltage of about 9V is available at its emitter.

The brightne power voltag ing off D-2. the D-2 Dist of D19's cat gulated volta

When transn switch (in th zero.

Likewise, fo is applied to about 9.5V i

During recep transmit/rec while the O zero. When through D1 and so a pro is delayed b receiving sec

RIT CIRCU

During rece on Q22, an The voltage trol R-2, an (receiving fi

In the case O22 while R96 to turn The voltage dial-set free quency at t

VXO UNIT The oscilla quency by

Resistors F to C34 are of the crys frequency

In this osc tripled aga local oscill The brightness of power-indicating lamp varies according to the power voltage. When the power voltage drops to a level under about 10V, the current to D19 and D-2 stops, turning off D-2. Thus the power voltage fluctuation and battery condition can be judged from the D-2 Display. For the receiving section's regulated voltage supply the reference voltage of D19's cathode is applied to Q12's (2SCD355) base through D16 (1S2473), and a regulated voltage of about 9.5V is obtained at its emitter.

When transmitting, R54 is grounded by the microphone PTT switch or mode change-over switch (in the case of CW-T), to make Q12's base voltage zero and output voltage also zero.

Likewise, for the transmit section regulated voltage, the reference voltage of D19 cathode is applied to Q14's (2SD355) base through D18 (1S2473), and a regulated voltage of about 9.5V is obtained at its emitter.

During reception, since the PTT switch is not grounded, positive voltage is applied on the transmit/receive change-over control Q13's (2SC945) base through R55 to turn on Q13, while the Q14's base is grounded through R56 and Q13, thus making the power voltage zero. When transmitting, the PTT switch is grounded and Q13's base is also grounded through D17 (1N60) to turn off Q13 and apply the reference voltage to Q14's base, and so a proper voltage is obtained. Also, the rise time for transmit/receive change-over is delayed by C74 and C75 respectively to prevent transmission signals from entering the receiving section during the change-over operation.

RIT CIRCUIT

1

During reception, positive voltage is applied to Q22's (2SC945) base through R95 to turn on Q22, and current flows through R18 in VXO unit, RIT control R-2, R97 and Q22. The voltage applied to D1 (MV201) of the VXO unit is varied by adjusting the RIT control R-2, and D1's capacity varies accordingly, thus enabling the local oscillator frequency (receiving frequency) to be changed.

In the case of transmission, since the voltage on Q22's base becomes zero to turn off Q22 while positive voltage is applied to Q23's (2SC945) base at the same time through R96 to turn on Q23, current flows through R18, R98, and Q23 all within the VXO unit. The voltage divided by R18 and R98 is applied to D1, and so transmission can be made at dial-set frequencies irrespective of the position of RIT control R-2. The receiving frequency at the RIT zero point can be corrected by adjusting R98.

VXO UNIT

The oscillator Q1(2SC373) in series with a crystal and variable capacitor, varies its frequency by changing the capacity of the variable capacitor.

Resistors RI to R4 are damping resistors to prevent abnormal oscillation. Capacitors C31 to C34 are linearity-adjusted for non-linearity of frequency changes caused by the errors of the crystal unit and variable capacitor. L1 to L4 and C1 to C4 adjust the oscillation frequency and band width.

In this oscillator, a 14MHz signal is oscillated fundamentally, tripled by Q2 (2SC373), tripled again by Q3 (2SC763) to a 133MHz signal with the level of 300mV as the first local oscillator. The band-pass filter composed of L7 to L9 minimizes spurious radiation.

Though the regulated voltage for the oscillator is supplied at a level of about 9 volts from Q15 of the main unit, it is further stabilized by the constant current circuit using Q4 (2SK19) and Zener diode D2 (WZ061). This voltage is supplied to Q1, Q2 and RIT circuit to further ensure sufficient frequency stability.

In the RIT circuit, the capacity of D1 to which a signal from R-2, RIT control, is given through R5, is changed. C6 and C30 are connected in series, which keeps the RIT shift to 3KHz.

ADJUSTMENT OF VARIOUS SECTIONS

This set is completely adjusted and checked so that it functions correctly. During prolonged use, however, the preadjusted condition might be affected by wear of parts, etc. If it is necessary to make adjustments at some time to regain specified performance, the following procedure may be followed.

Remember that changes in capacitor or coils will be very small, if any. Adjustments should not be attempted without adequate test equipment.

VXO UNIT ADJUSTMENT

- 1. Measuring Instruments for Adjustment:
 - * RF voltmeter (with above 1V full scale capability at 150MHz)
 - * Frequency counter (capable of measuring 150MHz)
 - * Multimeter (20Kohm per volt).
- 2. Frequency Adjustment:
 - Connect the frequency counter to J3 of the VXO unit, with ground connected to J2.
 - b. Place the RIT in the center position. Set the crystal switch to the position of the crystal to be aligned.
 - c. Set the typing dial to "100", and adjust the appropriate coil until the frequency shown in the chart is obtained.
 - Next set the dial to 200 and adjust trimmer (a) for the proper frequency according to the chart.
 - e. Set the dial now to "0" and adjust trimmer (b) for the proper frequency.
 - f. Repeat the adjustment above till no further adjustment is necessary to get the
 - proper frequencies at all three points.

a o paro		Dial	
Crystal No.	0	100	200
36-1	133.3015 MHz	133.4015 MHz	133.5015 MHz
36-2	133.5015	133.6015	133.7015
36-3	133.7015	133,8015	133.9015
36-4	133.9015	134.0015	134,1015
36-5 -,	134.1015	134.2015	134.3015
36-6	135,1015	135.2015	135.3015

- 1. Crystal i
- 2. Coil for
 - 3. Trimme
- 4. Trimmer
- 5. Crystal f
- 6. Coil for
- 7. Trimmer
- 8. Trimme

ADJUSTM

For receiving tion (the r the check p RF voltme tion, Furth dication of

RIT ADJU

In the rece (detent) the change it d



- 1. Crystal for 144.0MHz band
- 2. Coil for 144.0MHz band
- 3. Trimmer (a) for 144.0MHz band
- 4. Trimmer (b) for 144.0MHz band
- 5. Crystal for 144.2MHz band
- 6. Coil for 144.2MHz band
- 7. Trimmer (a) for 144.2MHz band
- 8. Trimmer (b) for 144.2MHz band

ADJUSTMENTS ON MULTIPLIER STAGES

For receiving, set the crystal selector to "144.2" and the tuning knob to the "200" position (the receiving frequency is 144.4MHz), connect a multimeter (for 3 volt range) to the check point R15 and tune L5 and L6 to maximum indication. Connect the probe of a RF voltmeter to the output terminal J3 of VXO and tune L7 and L9 to maximum indication. Further, readjust L5 and L6 and repeat this procedure to obtain the maximum indication of the RF voltmeter (250 – 300 mV).

RIT ADJUSTMENT

In the receive mode connect the frequency counter to J3, set the RIT knob to the center (detent) then record the frequency (the dial scale may be set at any position but do not change it during the adjustment).

- 9. Additional Crystal Sockets "A" and "B"
- 10. Coil for the "A" band
- 11. Trimmer (a) for "A" band
- 12. Trimmer (b) for the "A" band
- 13. Coil for the "B" band
- 14. Trimmer (a) for the "B" band
- 15. Trimmer (b) for the "B" band

Next, turn the MODE change-over switch to "CW-T" without connecting the key to the key jack, then read out the frequency. If it differs from the previously recorded frequency, adjust R98 on the main board to equalize both frequencies.

Repeat above adjustments to reduce the frequency difference between reception and transmission to under 10Hz.

TRANSMITTING SECTION ADJUSTMENT

a. Measuring Instruments for Adjustment

- * Terminal wattmeter (for about 10W full scale with 50 ohm impedance)
- * Frequency counter
- * RF voltmeter
- * AE oscillator
- * AF millivoltmeter
- * Multimeter (20Kohm per volt).

b. Final Stage Idle Current Adjustment

Turn the MODE change-over switch to "CW-T" without connecting the key to the key jack. Remove the solder of C136 and W22, and connect the multimeter, which is set at 100mA range, between these points. Adjust R90 so that the current becomes 30mA. After the adjustment, resolder the leads of C136 and W22.

c. Coil Adjustment

Connect the wattmeter to the external antenna socket, and set the transmit/receive frequency at "144,4MHz". With the MODE change-over switch turned to "CW-T", connect the key to the key jack and hold down the key, connect the RF voltmeter probe to the check point of R81 and adjust the cores of L14 to L19 alternately for a maximum voltmeter reading.

d. Driving and Final Stage Adjustments

Make sure that the power voltage is 13.8V under the same condition as in c. Turn the R92 rotor toward ground (to panel face) and adjust C120, C121, C127, C128, C137 and C138 so that the wattmeter indicates maximum (over 3W). After this, adjust R92 so that the wattmeter indicates exactly 3W. Set multimeter to volt range and connect to check point R105. Readjust L14 to L19 for maximum indication.

e. RF Meter Adjustment

Move D22 with respect to L26 (coupling) so that the meter indicates about 90% of full scale when the output is 3W at the completion of adjustment (d).

f. Carrier Frequency Adjustment

In receive, connect a frequency counter to check-point R28 and adjust C61 for 10.6985MHz. At this time, make sure that if the MODE change-over switch is turned to "CW-T," the frequency shifts about 1KHz upward. Then turn the MODE change-over switch to "REC" and connect the AF oscillator to the check point, R68. Ground the mike plug socket pin No.2 for SSB transmission, and set the AF oscillator oscillation frequency at 1.5KHz. Adjust the output level to 2.5W. Keeping the output level unchanged, alternately change the audio oscillator frequency from 300Hz to 3KHz, and fine adjust C61 to balance the output.

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d. Noi Set free mu gen mu

g. Mike Gain Adjustment

Connect the AF oscillator between the mike plug socket pins No.1 and No.4 (ground). Set its frequency at 1.5KHz and output level at 6mV.

Ground the mike plug socket pin No.2 and connect the AF millivoltmeter (300mV range) to the R68 check point and adjust R61 so that the meter reads 150mV. This adjustment can be slightly changed according to the use of microphone, strength of voice, condition, etc. Observation of the output carrier on a high frequency oscilloscope would be helpful while using normal microphone procedures in order to achieve optimum waveform and quality.

RECEIVING SECTION ADJUSTMENT

Measuring Instruments for Adjustment

- * Standard signal generator (for 144MHz band)
- * AF millivoltmeter
- * Multimeter

b. Sensitivity Adjustment

With the receiving frequency set at 144.4MHz and the volume knob in a reasonable volume position, connect the standard signal generator to the antenna connector and the AF millivoltmeter (1V range) to the AF output terminals J4 and J5 (ground).

(Never transmit during this adjustment because it may damage the signal generator attenuators).

Keeping the signal generator unmodulated, set the output level at about 30dB (μ V) and adjust the generator frequency to the receiving frequency. As a beat is heard from the speaker, fine-adjust the signal generator frequency or receiving frequency so that the beat becomes about 1000Hz. Try to keep the beat at this frequency during the adjustment.

Next, adjust L1-L10 cores successively to maximize the AF millivoltmeter indication, and if the AF millivoltmeter becomes full-scale, lower the signal generator output level without converting the meter range or turning the volume knob, etc. Repeat the adjustment until the AF millivoltmeter indicates over 800mV with the volume knob at maximum and S+N/N becomes over 10dB when the signal generator output level is -10dB (μ V).

c. S Meter Adjustment

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Adjust R48 so that the S meter indicates zero with no signal. Next, with the signal generator output level set at 90dB (μ V), adjust the frequency to the receiving frequency, and adjust R50 so that the S meter indicates full scale. After this adjustment is finished, lower the signal generator output level, and make sure that the signal generator output is within a range of 0dB ± 3dB when the S meter indicates S5.

d. Noise Blanker Adjustment

Set the signal generator output level at about 30dB (μ V), and adjust to the receiving frequency. Making sure that the beat is generated from the speaker, connect the multimeter (0.3V range) to the R39 check-point, and gradually lower the signal generator output level and adjust the L12 to a point where the indication is maximum.

SECTION VIII INSIDE VIEW

Whip Antenna				ส	
AF Filter	MP	C FA			Carrier Frequency Adjust
Meter Zero Adjust			·		IC, Balanced Modulator
Mic-Gain-Adjust				9	
Crystal Filter		N/	T.		RIT Adjust
TX Mixer IC			0.90		
Noise Blanker					ALC Adjust
MOS FET RF Amp.					Idling Current Adjust
Low-Pass Filter		° • •			Power Transistor
		A REAL PROPERTY AND A REAL	Can.		



SECTI

AF AMP # P C 575C2

DETECTOR 1 N60X4

AGC REC 1 N 60 1 S 24/3X2

> **AGC** 25 C943

NB CONTROL

NB AGC 28 CB4E

NOISE DET 1 NBUX2

NOISE AMP L A1221

NOISE AMP L A1721

SECTION IX BLOCK DIAGRAM

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SECTION X PARTS LIST

		N UNIT	
ef. No.	Description	Part No. Bo	ard Location
Q1	Transistor	2SA750 (1)	14
Q2	FET	3SK40-M	13
03	FET	2SK49-H2	H2
04	Transistor	2SC945-P	G1
Q5	Transistor	2SC945-P	F1
Q6	FET	MEM616-Y	CI
100 CT 11			
07	FET	MEM616-B	B2
Q8	Transistor	2SC945-P	A6
Q9	Transistor	2SC945-P	B6
Q10	Transistor	2SC945-P	B6
Q11	Transistor	2SC945-P	A5
Q12	Transistor	2SD355-E	E5
Q13	Transistor	2SC945-P	D5
Q14	Transistor	2SD355-E	D3
Q15	Transistor	2SC1209-E	E5
Q16	FET	2SK19-GR	C3
Q17	FET	3SK37-3	F5
Q18	Transistor	2SC383	GG
Q19	Transistor	2SC998	16
Q20	Transistor	2SC1947	J4
021			
Q22	Transistor	2SC945-S	D6
023	Transistor	2SC945-S	E6
IC1	IC	LA1221	83
IC2	ic	µPC575 C2	G3
102	IC	LA1221	HI
	ic		H1
104	1 853	LA1221	
1C5	IC	μPC566H	D2
IC6	IC	SN76514N	C5
1C7	IC	SN76514N	F3
D1	Diode	1SS53	F2
D2	Diode	15553	F2
D3	Diode	15553	C2
D4	Diode	15553	C2
D5	Diada	10100	C2
DG	Diode	1N60	B4
1.1.2 TO			17.79 (B. C. P.
D7	Diode	1N60	B4
D8	Diode	1N60	B4
D9	Diode	1N60	B4
D11	Diode	1N60	11
D12	Diode	1S2473	A5
D13	Diode	1N60	A4
D14	Diode	1\$2473	A5
D15	Diode	1\$2473	A5
D16	Diode	152473	E4
D17		1N60	D5
	Diode		
D18	Diode	152473	E4
D19	Diode	XZ-076	E4
D20	Diode	152473	15
D21	Diode	1N60	15
D22	Diode	1N60	- J3
D23	Diode	1S1555	H6
D24	Diode	151555	J5
D25	Diode	M1301	13
D26	Diode 1	15553	G2
		15553	G3
D27	Diode		
D28 D29	Diode Diode	WZ-056 1S1555	B1 D3

Ref. No.	N Descriptio	AAIN UNIT n Part No. Board Lo	ocatio
FL1	Xtal Filter	FEC-103-1 10.7MHz	E1
XI	Xtal	HC-18/U 10.6985MHz	A6
L1	Coil	LS-4	14
L2	Coil	LS-3A	12
L3	Cail	LS-3A	12
L4	Coil	LS-3A	H2
L5	Coil	LS-7	G2
LG	Coil	LS-7	G2
L7	Coil	LS-66A	C1
L8	Call	LS-66A	B1
L9	Coil	LS-66A	A2
L10	Cail	LS-68	B4
L11	Coil	L104 Choke	B 3
L12	Coil	LS-7	11
L13	Coil	L101 Choke	11
L14	Coil	LS-67	C3
L15	Coil	LS-67	E2
L16	Coil	LS-3A	F4
L17	Coil	LS-3A	G4
L18	Coil	LS-3A	F5
L10	Coil	LS-3A	FG
L20	Coil	LA-96	GG
	100703255	LA-71	H6
L21	Coll		10007
L22	Coil	LA-2	16 J6
L23	Coll	LA-9	
L24	Coil	LA-97	.15
L25	Coil	LA-9	J4
L26	Coil	LA-2	13
L27	Coil	LA-71	J2
L28	Coil	LA-71	J1
L29	Coil	L100 Choke	15
L30	Coil	L101 Choke	A3
L31	Coil	L101 Choke	A4
L32	Coil	L101 Choke	11
R1	Resistor	470 ohm ELR25	
R2	Resistor	4.7K ohm ELR25	14
R3	Resistor	100K ohm ELR25	13
R4	Resistor	100K ohm ELR25	H3
R5	Resistor	100K ohm ELR25	13
R6	Resistor	47 ohm ELR25	H3
B7	Resistor	22 ohm ELR25	12
R8	Resistor	1K ohm ELR25	H2
R9	Resistor	220 ohm ELR25	G1
R10	Resistor	4.7K ohm ELR25	G1
B11	Resistor	10K ohm ELR25	F1
R12	Resistor	12K ohm ELR25	F2
B13	Resistor	39K ohm ELR25	F2
B14	Resistor	10K ohm ELR25	D2
R15	Resistor	10K ohm ELR25	D1
R16	Resistor	22K ohm ELR25	C1
R17	Resistor	100K ohm ELR25	CI
R18	Resistor	100K ohm ELR25	CI
R19	Resistor	100 ohm ELR25	B2
R20	Resistor	220 ohm ELR25	B1
B21	Resistor	6.8K ohm ELR25	B1
R22	Resistor	10K ohm R25	CI
B23	Resistor	470 ohm ELR25	AI
15 2 3	rtesistor	470 0000 00023	- 61

Ref. No.	De
R24	Resis
R25	Resis
R26	Resis
R27	Resis
R28	Resis
R29	Resis
R30	Resis
R31	Resis
R32	Resis
R33	Resis
R34	Resis
R35	Resis
R36 R37	Resis Resis
R38	Resis
R39	Resis
R40	Resis
841	Resis
B42	Resis
R43	Resis
R44	Resis
R45	Resis
FI46	Resis
R47	Resis
R48	Trim
R49	Resis
R50	Trim
R51	Resis
R52	Resis
R53	Resis
R54	Resis
R55	Resis
R56	Resis
R57	Resis
R58	Resis
R59	Resis
R60	Resis
R61	Trim
R62	Resis
R63	Resis
R64	Resis
R65	Resis
R66 R67	Resis Resis
R67	Resis
R69	Resis
R70	Resis
871	Resis
872	Resis
R73	Resis
R74	Resis
R75	
R76	Resis
R77	Resis
R78	Resis
R79	Resis
R80	Resis
R81	Resis
882	Resis

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Ref. No.	Description	Part No.	Board Lo	ocation	Ref. No.	Description	Part No.	Board L	ocation
B24	Resistor	220 ohm	ELR25	B2	Das		100 and 100 and 100 and	-	~ ~
R25	Resistor	4,7K ohm	ELR25	A2	R83	Resistor	47 ohm	ELR25	G6
					R84	Resistor	1.8K ohm	ELR25	H6
R26	Resistor	220 ohm	ELR25	A2	R85	Resistor	10 ohm	R25	H6
B27	Resistor	4.7K ohm	ELR25	H2	R86	Resistor	680 ohm	ELR25	H5
R28	Resistor	470 ohm	R25	B4	R87	Resistor	150K ohm	ELB25	H3
R29	Resistor	470 ohm	ELR25	B4	R88	Resistor	47 ohm	R25	J5
R30	Resistor	820 ohm	ELR25	B4	R89		220 ohm		
R31	Resistor	39K ohm	ELR25	B3	10000000	Resistor		ELR25	15
R32	Resistor	4,7K ohm	ELR25	E3	R90	Trimmer	500 ohm	FR10P	H5
R33	Resistor	270 ohm	ELR25	G3	R91	Resistor	220 ohm	ELR25	G5
				22242	R92	Trimmer	5K ohm	ELR25	H5
R34 R35	Resistor	100 ohm	ELR25	A4	R93	Resistor	470 ohm	R½	13
	Resistor	120K ohm		H4	R94	Resistor	220 ohm	ELR25	J5
R36	Resistor	2.2K ohm	ELR25	G1					
R37	Resistor	1K ohm	ELR25	H1	R95	Resistor	10K ohm	ELR25	D6
R38	Resistor	10K ohm	ELR25	G1	R96	Resistor	10K ohm	ELR25	E5
R39	Resistor	22K ohm	R25	F1	R97	Resistor	8,2K ohm	ELR25	D6
R40	Resistor	27K ohm	ELR25	F2	R98	Trimmer	10K ohm	FR10B	E6
R41	Resistor	4.7K ohm	ELR25	A6	R99	Resistor	4.7K ohm	ELR25	G2
R42	Resistor	4.7K ohm	ELR25	AS	R100	Resistor	68 ohm	ELR25	G3
R43	Resistor	22K ohm	ELR25	B6	R101	Resistor	10K ohm	ELR25	G4
R44	Resistor	22K ohm	ELR25	A6	R102	Resistor	4.7K ohm	ELR25	G3
R45	Resistor	3.3K ohm	ELR25	B6	R103	Resistor	2.7K ohm	ELR25	G6
R46	Resistor	4,7K ohm	ELR25	B5	B104	Resistor	2,2K ohm	R25	G6
B47	Resistor	1K ohm	ELR25	B5	R105	Resistor	47K ohm	R25	C3
R48	Trimmer	1K ohm	FR10B	C3	R106	Resistor	2,2K ohm	ELR25	83
R49	Resistor	2.2K ohm	ELR25	B2	18040	8.000000000	2020302010256	1410-1810	10.935
R50	Trimmer	5K ohm	FR10B	B3	C1	Ceramic	0.01µF	50V	14
R51	Resistor	1.8K ohm	ELR25	A5	C2	Ceramic	10pF	50V	H4
R52	Resistor	10 ohm	ELR25	E4	C3	Ceramic	0.01µF	50V	13
R53	Resistor	4.7K ohm	ELR25	E4	C4	Ceramic	0.01µF	50V	H3
R54	Resistor	22 ohm	ELR25	E5	C5	Ceramic	0.01µF	50V	13
R55	Resistor	22K ohm	ELR25	D4	CG	Ceramic	7pF	50V	12
R56	Resistor	22 ohm	ELR25	D4	C7	Ceramic	0.01µF	50V	13
R57	Resistor	4,7K ohm	ELR25	D4	C8	Ceramic	0.35pF	50V	12
R58	Resistor	22 ohm	ELR25	D4	C9	Ceramic	6pF	50V	12
R59	Resistor	470 ohm	ELR25	E5	C10	Ceramic	0.35pF	50V	H2
R60	Resistor 🧔	22 ohm	ELR25	E5	C11	Ceramic	7pF	50V	H2
R61	Trimmer	500 ohm	FR10B	E2	C12	Ceramic	0.01µF	50V	H2
R62	Resistor	15K ohm	ELR25	E3	C13	Ceramic	1pF	50V	H1
R63	Resistor	150K ohm		D2	C14	Ceramic	0.01µF	50V	G2
R64	Resistor	56K ohm	ELR25	D3	C15	Ceramic	4pF	50V	G1
R65	Resistor	2,2K ohm	ELR25	E2	C16	Ceramic	500pF	50V	F2
R66	Resistor	560 ohm	ELR25	D3	C17	Ceramic	0.01µF	50V	H1
R67	Resistor	330 ohm	ELR25	D3	C18	Ceramic	0.01µF	50V	F2
R68	Resistor	2.7K ohm	R25	D5	C19	Ceramic	0.01µF	50V	D2
R69	Resistor	100 ohm	ELR25	D4	C20	Ceramic	0.01µF	50V	DI
R70	Resistor	47K ohm	ELR25	H3	C21	Ceramic	0.01µF	50V	C1
R71	Resistor	100 ohm	ELR25	C2	C22	Ceramic	0.01µF	50V	C2
R72	Resistor	150 ohm	ELR25	C2	C23		0.0.161		
R73	Resistor		ELR25	C3	C24	Ceramic	0,001µF	50V	C1
R74	Resistor	220 ohm 10K ohm		1.	C24	Ceramic	0.001µF	50V	CI
			ELR25	E3	C25	Ceramic	0.01µF	50V	C2
R75	- Desister	47.0	DI DOC	0.00	10.000	Geranne	0.010	30.0	42
R76	Resistor	47 ohm	ELR25	E3	C27	Couperla	0.001	5017	В2
B77	Resistor	100K ohm		F4	C28	Ceramic	0,001µF	50V	
R78	Resistor	100K ohm		F5	C29	Ceramic	0.01µF	50V	B1
R79	Resistor	100 ohm	ELR25	F5	C30	Ceramic_	0.01µF	50V	B2
R80	Resistor	100 ohm	ELR25	G5	C31	Ceramic	0.01µF	50V	B2
R81	Resistor	470 ohm	R25	F6	C32	50 PT	012-12-5 10-12-5	20000	10000
R82	Resistor	47 ohm	R25	F6	C33	Ceramic	0.01µF	50V	A2

Ref. No.		UNIT	Barrel	Location	0.7.00	C 1272 - A 21 - C 200 - C 2	N UNIT	Dec. 1	
ter, No.	Description	Part No.	Board	Location	Ref. No.	Description	Part No.	Board I	ocation
C34	Ceramic	10pF	50V	83	C94	Electrolytic	10#F	16V	D4
C35	Ceramic	0.01µF	50V	83	C95	Ceramic	0.01µF	50V	C2
C36	Ceramic	120pF	50V	B4	C96	Ceramic	0.01µF	50V	C3
C37	Ceramic	0.01µF	50V	B4	C97	Ceramic	45pF	50V	F2
C38	Semiconductive	0.2µF	12V	B4	C98	Ceramic	0.01µF	50V	E3
C39	Mylar	0.056µF	50V	C4	C99	Ceramic	0.01µF	50V	F3
C40	Mylar	0.056µF	50V	C4	C100				F2
C41			50V	20.20	C100	Ceramic	0.01µF	50V	
	Electrolytic	1µF		H3	1202030710	Ceramic	0.01µF	50V	F3
C42	Ceramic	0.01µF	50V	D6	C102	Ceramic	0.01µF	50V	F3
C43	Electrolytic	10µF	16V	G3	C103	Ceramic	0.01µF	50V	F3
C44	Ceramic	0.01µF	50V	EG	C105	Electrolytic	10µF	16V	F3
C45	Ceramic	0.001µF	50V	H3	C106	Ceramic	8pF	50V	F4
C46	Electrolytic	47µF	16V	G3	C107	Ceramic	0.01µF	50V	G5
C47	Electrolytic	47µF	16V	H4	C108	Ceramic	6pF	50V	G4
C48	Electrolytic	100µF	10V	G4	C109	Electrolytic	10µ F	16V	F5
C49	Semiconductive	0,2µF	12V	G4	C110	Ceramic	0.01µF	50V	E5
C50	Ceramic	0.01µF	50V	G1	C111	Ceramic	0.01µF	50V	G5
C51	Electrolytic	1µF	50V	GI	C112	Ceramic	0.01µF	50V	G5
C52	Ceramic	0.001µF	50V	H1	C113	Ceramic	6pF	50V	F5
C53	Ceramic	0,01µF	50V	H1	C114	Ceramic	6pF	50V	F6
C54	Ceramic	0.01µF	50V	H1	C115	Ceramic	Contraction of the second s		
C55				2.2.2	11 No.5 (1998) To	12/20/20/20/20/20/20/20/20/20/20/20/20/20	8pF	50V	F6
	Ceramic	0.001µF	50V	11	C116	Ceramic	120pF	50V	F6
C56	Ceramic	50pF	50V	11	C117	Electrolytic	10µF	16V	G5
C57	Ceramic	50pF	50V	12	C118	Ceramic	0.01µF	50V	G6
C58	Ceramic	0.001µF	50V	F1	C119	Ceramic	0,01µF	50V	G6
C59	Ceramic	0.01µF	50V	G1	C120	Trimmer	CV05C120		
C60	Ceramic	0.01µF	50V	A5	C121	Trimmer	CV05D180	(18pF) H6
C61	Trimmer	CV05E300	130pF) 86	C122	Electrolytic	10µF	16V	H6
C62	Ceramic	68pF	50V	85	C123	Ceramic	0.01µF	50V	H5
C63	Ceramic	30pF	50V	A6	C124	Ceramic	0.01µF	50V	15
C64	Styrene	200pF	50V	B6	C125	Electrolytic	10µF	16V	16
C65	Styrene	100pF	50V	B5	C126	Feed Through	1000pF	50V	16
C66	Ceramic	0,01µF	50V	85	C127	Trimmer	CV05D120		16
C67	Ceramic	60pF	50V	B5	C128	Trimmer	CVE50-11		J6
C68	Ceramic	50pF	50V	B5	C129	Ceramic	15pF	50V	15
C69	Bi Polar	4,7 µР	25V	A5	C130	Ceramic	ALC: 17700 V 2014		
C70	Electrolytic	4.7 μr 1μF	50V	A4	100000 State 20		0.01µF	50V	H5
C71		55,500 Charles	50V	P1020312	C131	Electrolytic	4.7µF	16V	H5
	Ceramic C.	0.01µF		B4	C132	Electrolytic	10µF	16V	15
C72	Ceramic	0.01µF	50V	B5	C133	Ceramic	0.01µF	50V	15
C73	Ceramic	0.001µF	50V	A4	C134	Ceramic	0.01µF	50V	14
C74	Electrolytic	10µF	16V	E5	C135	Electrolytic	10µF	16V	J4
C75	Electrolytic	10µF	16V	E3	C136	Feed Through	1000pF	50V	14
C76	Ceramic	0.01µF	50V	E4	C137	Trimmer	CV05D180	{18pF	J4
C77	Electrolytic	10µF	16V	E5	C138	Trimmer	CVE50-11	(50pF)	J3
C78	Ceramic	0.01µF	50V	E5	C139	Ceramic	0.01µF	50V	13
C79	Mylar	0.002µF	50V	D2	C140	Ceramic	15pF	50V	J2
C80	Ceramic	0.01µF	50V	E2	C141	Ceramic	6pF	50V	J2
C81	Ceramic	500pF	50V	D3	C142	Ceramic	30pF	50V	J2
C82	Electrolytic	47µF	6.3V	D2	C143	Ceramic	2pF	50V	J2
C83	Ceramic	0.01µF	50V	D3	C143	Ceramic	20pF	50V	J2
C84	Electrolytic	10µF	16V	D2	C144	0000E00000E000A			
C85					10 10 10 10 10 10 10 10 10 10 10 10 10 1	Ceramic	25 C. (S.) C. (S.).	50V	15
	Bi Polor	4.7µF	25V	C3	C146	Ceramic	0.01µF	50V	G5
C86	Electrolytic	10µF	16V	C5	C147	Ceramic	0.01µF	50V	G2
C87	Ceramic	0.01µF	50V	B5	C148	Ceramic	0.01µF	50V	G3
C88	Ceramic	0,01µF	50V	C5	C149	Ceramic	0.001µF	50V	13
C89	Ceramic	0.01µF	50V	C5	C150	Ceramic	0.04µF	50V	E4
C90	Ceramic	45pF	50V	C4	C151	Ceramic	7pF	50V	F4
C91	Ceramic	0.01µF	50V	C3	C152	Ceramic	0.01µF	50V	62
		0.01µF	50V	D4	C153	Ceramic	10pF	50V	15
C92	Ceramic	0.0141							12

-
Electrolytic
Electrolytic
Ceramic
VX
Description
Pin Contact
Transistor
Transistor
Transistor
FET
Diode
Diode
Diode
Xtal
Xtal
Coil
Resistor
-
Resistor
Trimmer
Trimmer
Trimmer
Trimmer

C155	Electrolytic	33µF	10V	13
C156	Electrolytic	4.7µF	10V	H4
C157	Ceramic	10pF	50V	J4
C158	Ceramic	0.01µF	50V	13
C159	Ceramic	0,01µF	50V	B1
C160	Ceramic	0.01µF	50V	F5
C161	Ceramic	0.01µF	50V	14
	vx			
Ref, No.	Description	Part No.	Board Lo	cation
J1	Pin Contact	60809-1		
J2	Pin Contact	60809-1		
J 3	Pin Contact	60809-1		
J4	Pin Contact	60809-1		
J5	Pin Contact	60809-1		
J6	Pin Contact	60809-1		
Q1	Transistor	2SC373		C2
02	Transistor	2SC373		C3
03	Transistor	2SC763-C		B2
Q4	FET	2SK19Gr		C2
D1	Diode	- MV-201		E1
D2	Diode	WZ-061		C2
X1	Xtal	HC-18/U 3	6-1	F2
X2	Xtal	HC-18/U 3		F2
L1	Coil	LB-288		F1
L2	Coil	LB-28B		F1
L3	Coil	LB-28B		E1
L4	Coil	LB-28B		D1
L5	Coil	LS-2		B 3
LG	Coil	LS-2		B 3
L7	Coil	LS-3A		В1
L8	Coil	LS-3A		B1
L9	Coil	LS-3A		A2
R1	Resistor	100K ohm	ELR25	G3
R2	Resistor 🦾	100K ohm	ELR25	F2
R3	Resistor	100K ohm	ELR25	E3
R4	Resistor	100K ohm	ELR25	E3
R5	Resistor	220K ohm	R25	F1
R6	Resistor	10K ohm	ELR25	D2
B 7	Resistor	22K ohm	ELR25	C2
R8	Resistor	470 ohm	ELR25	D3
R9	Resistor	10K ohm	ELR25	C3
R10	Resistor	22K ohm	ELR25	D3
R11	Resistor	330 ohm	ELR25	C3
R12	Resistor	220 ohm	ELR25	82
R13	Resistor	3.9K ohm	ELR25	B2
B14	Resistor	15K ohm	ELR25	B2
R15	Resistor	330 ohm	R25	82
R16	Resistor	220 ohm	ELR25	B2
R17	realator	220 0101	261120	672
R18	Resistor	4,7K ohm	ELR25	D3
C1	Tulana	CV05C120	112661	62
C1	Trimmer		A DESCRIPTION OF THE OWNER OF THE	62 52
C2	Trimmer	CV05C120	Sect. 90 M \$100 Autors	F2
C3	Trimmer	CV05C120		E2
C4	Trimmer	CV05C120		E2
C5	Variable	C321A(Ga	ndecti	CI

mic mic mic mic mic mic mic mic mic mic		10pF CH 0.01µF 100pF Y 200pF X 200pF X 200pF X 200pF X 200pF X 0.01µF 40pF PH 45pF 0.01µF 45pF 0.01µF 8pF 6pF 8pF 0.35pF 0.01µF 33µF 0.01µF	L 50 L 50 L 50 L 50 L 50 L 50 50 50 50	~~~~~	D1 G1 C2 D2 C2 C3 C3 C3 C3 C3 B3 B3 B3 B3 B2 B2 B2 B2 B2 B2 B2 B1 A1 A1 A1
mic mic mic mic mic mic mic mic mic mic		0.01µF 100pF Y 10pF CF 200pF X 200pF X	L 50 L 50 L 50 L 50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	G1 C2 C2 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3
mic mic mic mic mic mic mic mic mic mic		100pF Y 10pF CF 200pF X 200pF X 200pF X 200pF X 0.01µF 40pF PH 45pF PH 45pF PH 45pF 0.01µF 8pF 8pF 8pF 8pF 0.35pF 0.01µF 33µF	L 50 L 50 L 50 S0 50 50 50 50 50 50 50 50 50 50 50 50 50	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	C2 C2 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3 C3
mic mic mic mic mic mic mic mic mic mic		10pF CF 200pF X 200pF X 200pF X 200pF X 0.01µF 40pF PH 0.01µF 45pF PH 45pF PH 45pF 0.01µF 8pF 6pF 8pF 0.35pF 0.01µF 33µF	I 50 L 50 L 50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	D2 C2 D3 C3 C3 C3 B3 B3 B2 B2 B2 B2 B2 B1 A1 A1
mic mic mic mic mic mic mic mic mic mic		200pF X 200pF X 200pF X 0,01µF 40pF PH 0,01µF 45pF PH 45pF PH 45pF 0,01µF 8pF 8pF 8pF 0,35pF 0,01µF 33µF	L 50 L 50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~	C2 D3 C3 C3 C3 B3 B3 B2 B2 B2 B2 B2 B1 A1 A1
mic mic mic mic mic mic mic mic mic mic		200pF X 200pF X 0,01µF 40pF PH 0,01µF 1pF 45pF PH 45pF PH 45pF 0,01µF 8pF 6pF 8pF 6pF 8pF 0,35pF 0,35pF 0,01µF 33µF	L 50 L 50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~	D3 C3 C3 C3 B3 B3 B2 B2 B2 B2 B2 B1 A1 A1
mic mic mic mic mic mic mic mic mic mic		200pF X 0.01µF 40pF PH 0.01µF 1pF 45pF PH 45pF 0.01µF 8pF 6pF 8pF 0.01µF 8pF 0.35pF 0.01µF 33µF	L 50 50 50 1 50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	C3 C3 C3 B3 B3 B2 B2 B2 B2 B2 B1 A1 A1
mic mic mic mic mic mic mic mic mic mic		0.01µF 40pF PH 0.01µF 1pF 45pF PH 45pF 0.01µF 8pF 8pF 8pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	C3 C3 B3 B3 B2 B2 B2 B2 B1 A1
mie mie mie mie mie mie mie mie mie mie		40pF PH 0.01µF 1pF 45pF PH 45pF 0.01µF 8pF 6pF 8pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50 50 50 50 50 50 50 50 50 5	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	C3 C3 B3 B2 B2 B2 B2 B1 A1
mic mic mic mic mic mic mic mic mic mic		0.01µF 1pF 45pF PF 45pF 0.01µF 0.01µF 8pF 8pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50 50 50 50 50 50 50 50	v v v v v v v v v v v v v v v v v v v	C3 B3 B2 B2 B2 B2 B1 A1
mic mic mic mic mic mic mic mic mic mic		1pF 45pF PH 45pF 0.01µF 8pF 6pF 8pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50 50 50 50 50 50 50		83 82 82 82 82 82 81 A1 A1
mic mic mic mic mic mic mic mic mic mic		45pF PH 45pF 0.01µF 0.01µF 8pF 6pF 8pF 0.35pF 0.01µF 33µF	H 50 50 50 50 50 50 50 50 50 50 50		83 82 82 82 82 81 A1 A1
mic mic mic mic mic mic mic mic mic mic		45pF 0.01µF 0.01µF 8pF 6pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50 50 50 50	~~~~~~	82 82 82 82 81 A1 A1
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mic mic mic mic mic mic trolytic mic mic mic mic mic mic mer		0.01µF 0.01µF 8pF 6pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50 50 50 50	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	82 82 82 81 A1 A1
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mic mic mic mic mic trolytic mic mic mic mic nmer nmer		8ρF 6pF 8pF 0.35pF 0.01μF 33μF	50 50 50 50 50 50	v v v v	82 81 A1 A1
mic mic mic mic trolytic mic mic mic mic nmer nmer		6pF 8pF 8pF 0.35pF 0.01µF 33µF	50 50 50 50 50	v v v v	B1 A1 A1
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mic mic trolytic mic mic mic mer mer		8рF 0.35pF 0.01µF 33µF	50 50 50	v v	A1
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trolytic mic mic mic mic mer mer mer		33µF		¥	-
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imic umer umer umer umer			50	V	E3
imic umer umer umer umer		0.01µF	50	v	C2
nmer nmer nmer nmer		5pF CH	50		E1
nmer nmer nmer		CV05A0			G2
nmer nmer			22212-02-015		F2
nmer		CV05A0			
		CV05A0			E2
		CV05A0	- C.O.S.		E2
mic		5pF CH	50		D1
imic		0,01µF	50	V	D2
mic		0.001µF	50	V	C2
ch		ESR-E13	34K20	z	
Contact		60809-1			E3
Contact		60809-1			A2
Contact		60809-1			A3
Contact		60809-1			82
Contact		60809-1	<u>}</u>		F1
Socket					D2
Socket					D2
Socket					E2
Socket		380-598	2		E2
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SECTION XI OPTIONS

We have prepared a variety of options for the portable transceiver IC-202E in order to enlarge its use as a portable, mobile and fixed set.



RECHARGEABLE **BATTERY PACK** BATTERY CHARGER BC-20 BATTERY N-900C x 10 26 (900 mAh)

MOBILE MOUNTING BRACKET (B) FOR IC-202E



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KIT FOR IC-20L







VOLTAGE CHART

				Transistor FET													
Unit	Q No.	Mod	de	(B)	10	C)	(1	E)	łG	11	10	32)	(D)		(S)	Re	marks
	01	R		8.2	VG 10	8.9	8.										
	01	Т		C		0	1.6	D			l					i i	
	02	R							0		4	,2	9,0		0.23		
	03	R			20 B	1200		. 1	0				9.0		0.86		1 01
	04	R		0		2.1	E									- A.C.1	-ON
	05	R		0	20	6.7	6		-	65	1 8	3	8,8		0.35	198	3-ON
	Q6 Q7	B							0			.2	8,8		0.65		
	08	B		0.7	,	0	E	2 I.	U	2	2	0	0.0		0.05		
	08	T		0.7	1.1	ō	E							- 12		CV	V-T
	0.9	B		5,0		7.0	4.									355	S 40
	010			4.4		7.0	3.	244.0									
	Q11			0.05		E		0									
	Q11			0.05		Е		0									
	Q12			9,9		12.2	9.	2									
	012	T		C) .	13.0		0					¥				
	Q13	8		0.65	5	0	E	e 1									
Main	Q13			0.23	3	9,8	E										
Unit	Q14			(13.2		0									
	Q14			9.8		11.3	9.	- 22 C								1	
	Q15			9,3	3	12.2	8.	7								1	
	Q16								C		1 33		6.4		0,7		
	Q17			0.9	a 10	10120	1		0)	1 9	1	8,8	8	0,45		
	018					13.2		0			÷						
	Q18			1.3		12.6	0.										
	019			0.75		13.2	E										
	Q19 Q20			0.72		13.2 13.2	E						1				
	020			0.75		13.2	E						1				
	021			0.74	÷٠	1.0.1	1 2	5 I I									
	021																
	022			0.67	1	0	E										
	022			(3.7	E										
	023)	4.8	E										
	023	T		0.67	/	0	E										
77505.65	Q1	R8	1101	1.8		6.1		3			Î						
vxo	Q2	R&		1.7		7.8		3									
Unit	Q3	R&	T	1.6	5	7.7	1.	55									
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IC : IC 4	s 1			IC 6 IC 7					- 0	C 2					6.	: 5	
6550				-2502		_	Pin N	0			_						
Unit	IC No.	Mode	1	2	3	4	5	6	7	8	9	10	11	12	13	14	
	IC1	B	9.3	9.3	2:05	E								_			
	IC2	B	1.4	13.0	12.3	7.3	6.1	13.0	0.21	1.7		11				1 3	
	IC2	т	1.5	13.0	12.8	0	0.55		0	4.8		1.1					
	īc3	R	6.6	9.3	2.05	E			100400	1							
Main	IC4	R	9.3	9,3	2.05	Е											
	IC5	т	1.5	0.7	0.1	Е	0.85	1.3	9.2								
	IC6	Т	0	8,8	7.8	4.5	2.9	Е	Е	E	1.	4,5		4.5	7.8	E	SERVICE
	100	T	D	8.4	6.0	5,5	4.9	E	E	E	4.7	5,4	5.5	5.5	6.0	E	CW-
33	IC6 IC7	Ύτ.	E	8.8	7.8	4.5	2.9	E	E	E	2,9	4.5	4.5	4.5	7.8	E	100000000000000000000000000000000000000









